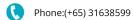
Balanced InGaAs Photodiodes to 25 GHz







Company Address:288 Woodlands Loop #04-00, Singapore 738100





Overview

The BPD25 is "push-pull" InGaAs photodiodes with each photodiode capable of handling high optical power up to +14 dBm. High Common Mode Rejection Ratio (CMRR) and low Polarization Dependent Loss (PDL) make these devices ideal for both digital and analog applications. The broad wavelength response of these photodiodes allows for multiple wavelength usage.

Features

- Lowest PDL (typical 0.05 dB)
- Normalized CMRR exceeds 30 dB
- Useable spectral wavelength range of 800-1650 nm
- Improves sensitivity by canceling DC portion of RIN and ASE noise
- High optical power handling InGaAs PIN photodiodes
- Small form-factor fiber-pigtailed package
- Improved reliability for high optical power handling
- One device for multiple wavelengths reduces operational and inventory cost
- OIP3 exceeding + 40dBm for highly linear option

Product Specifications

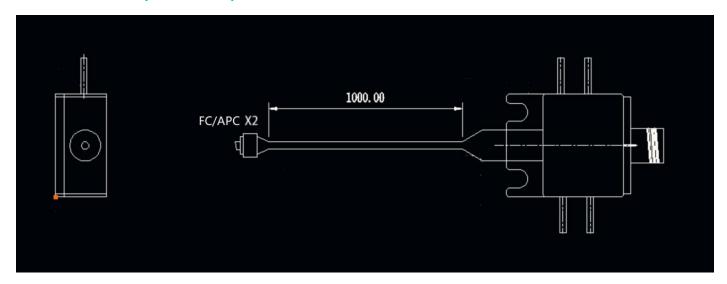
(Unless otherwise specified, all tests are conducted at 25°C)

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Operating Temperature	T0		0		75	\mathbb{C}
Storage Temperature	Ts		-40		85	\mathbb{C}
Operating Wavelength	λ			1550		nm
Bias Voltage	Vb		3	5		V
Photosensitive Diameter	Ф			20		μm
Saturation Optical Power	Ps	λ = 1550 nm, Vb = 5 V	9	10		dBm
Responsivity	R	λ = 1550 nm, Vb = 5 V		0.7		A/W
Responsivity Imbalance	lmb			1.50%		
Dark Current	ld	Vb = 5 V		5	10	nA
3 dB Bandwidth	BW	Ps,o = 0 dBm, Vb = 5 V	25	26		GHz
Common Mode Rejection Ratio	CMRR	Ps,o = 0 dBm, Vb = 5 V	18	20		dB

Maximum Absolute Ratings

Parameter	Symbol	Rating	Unit
Optical Power	Ps	13	dBm
Forward Voltage	Vr	10	V
Operating Temperature	Тор	-40 ~ +70	°C
Storage Temperature	Tstg	-40 ~ +85	°C
Soldering Temperature	Тр	260 (10s)	°C
Minimum Fiber Bending Radius	Rfiber	20	mm

Dimensions (unit mm)



Custom sizes and pins are available upon request, with the minimum size being 16*16*8mm (with pigtails, pins, and mounting details).